

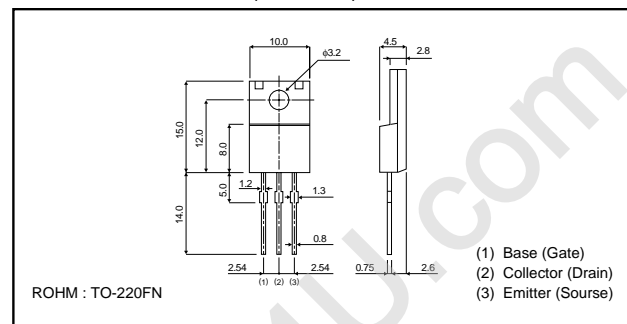
# Power Transistor (−80V, −4A)

## 2SB1568

### ● Features

- 1) Available in TO-220 FN package
- 2) Darling connection provides high dc current gain ( $h_{FE}$ )
- 3) Damper diode is incorporated
- 4) Built in resistors between base and emitter
- 5) Two millimeters lower than TO-220 FP which allows higher density mounting
- 6) Complementary pair with 2SD2399

### ● External dimensions (Unit : mm)



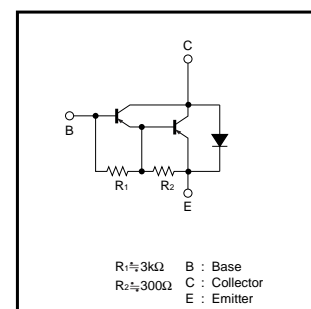
### ● Applications

Power amplifier

### ● Absolute maximum rating ( $T_a=25^\circ\text{C}$ )

Parameter	Symbol	Limits	Unit
Collector-base voltage	$V_{CBO}$	−80	V
Collector-emitter voltage	$V_{CEO}$	−80	V
Emitter-base voltage	$V_{EBO}$	−7	V
Collector current	$I_C$	−4	A(DC)
	$I_{CP}$	−6	A(Pulse)*
Collector dissipation	$P_C$	2	W( $T_a=25^\circ\text{C}$ )
		30	W( $T_c=25^\circ\text{C}$ )
Junction temperature	$T_j$	150	$^\circ\text{C}$
Storage temperature	$T_{stg}$	−55 to +150	$^\circ\text{C}$

### ● Equivalent circuit



### ● Electrical characteristics (unless otherwise noted, $T_a=25^\circ\text{C}$ )

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Collector-base breakdown voltage	$BV_{CBO}$	−80	—	—	V	$I_C = -50\mu\text{A}$
Collector-emitter breakdown voltage	$BV_{CEO}$	−80	—	—	V	$I_C = -1\text{mA}$
Collector cutoff current	$BV_{EBO}$	−7	—	—	V	$I_E = -5\text{mA}$
Emitter cutoff current	$I_{CBO}$	—	—	−100	$\mu\text{A}$	$V_{CB} = -80\text{V}$
DC current gain	$I_{EBO}$	—	—	−3	mV	$V_{EB} = -5\text{V}$
Collector-emitter breakdown voltage	$h_{FE}^{*1}$	1000	5000	−3	—	$V_{CE} = -3\text{V}$ , $I_C = -2\text{A}$
Collector-emitter saturation voltage	$V_{CE(sat)}^{*1}$	—	−1.0	10000	V	$I_C/I_B = -2\text{A}/-4\text{mA}$
Transition frequency	$f_T^{*1*2}$	—	12	−1.5	MHz	$V_{CE} = -5\text{V}$ , $I_E = 0.5\text{A}$ , $f = 10\text{MHz}$
Output capacitance	$C_{ob}$	—	35	—	pF	$V_{CB} = -10\text{V}$ , $I_E = 0\text{A}$ , $f = 1\text{MHz}$

\*1 Measured using pulse current.

\*2 Transition frequency of the device.

## Transistors

## ●Packaging specifications

Type	h <sub>FE</sub>	Packaging	Bulk
		Code	
		Basic ordering unit(pieces)	500
2SB1568	1000 to 10000		○

## ●Electrical characteristics

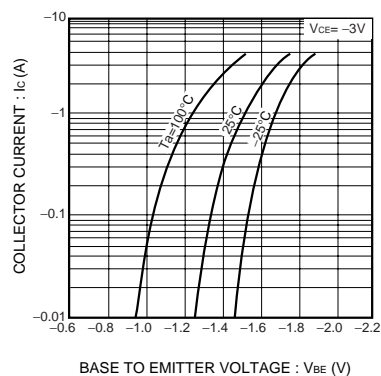


Fig.1 Grounded emitter propagation characteristics

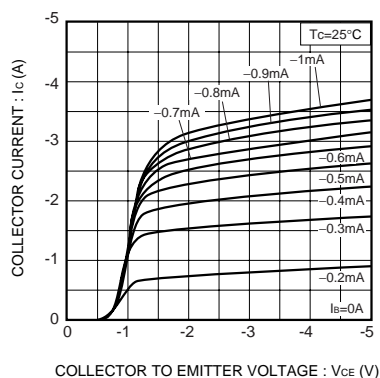


Fig.2 Grounded emitter output characteristics ( I )

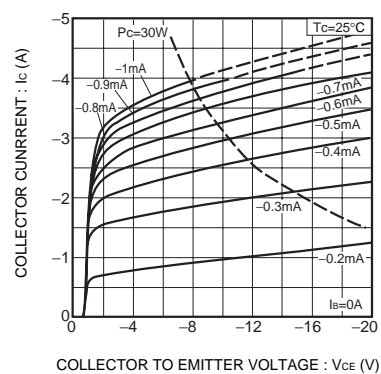


Fig.3 Grounded emitter output characteristics ( II )

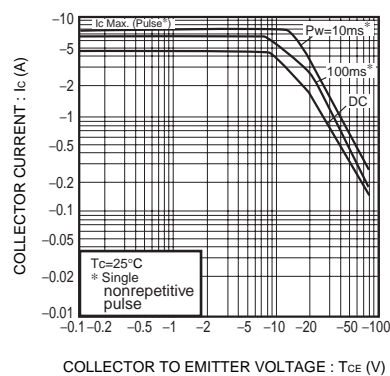


Fig.4 Safe operating area

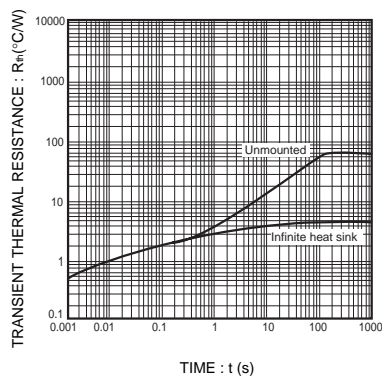


Fig.5 Transient thermal resistance

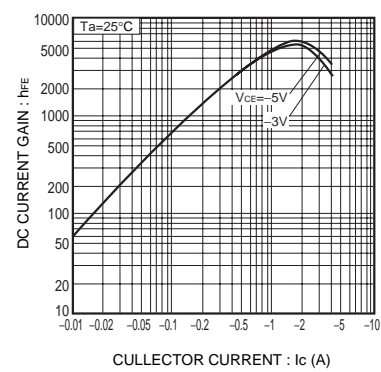


Fig.6 DC current gain vs. collector current ( I )

## Transistors

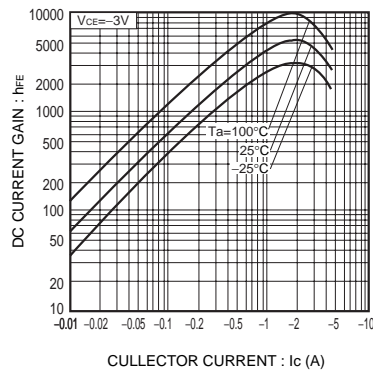


Fig.7 DC current gain vs.  
collector current ( II )

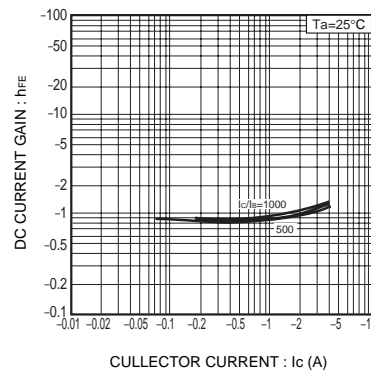


Fig.8 Collector-Emitter saturation  
voltage vs. collector current ( I )

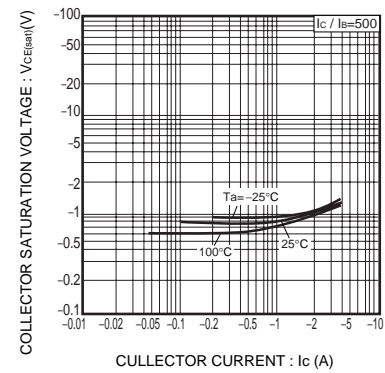


Fig.9 Collector-Emitter saturation  
voltage vs. collector current ( II )

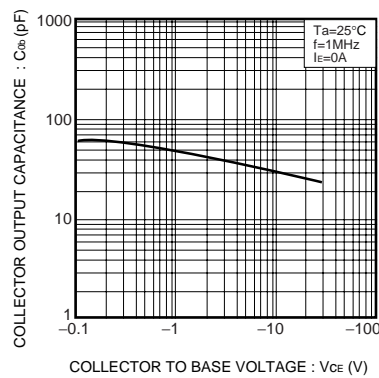


Fig.10 Collector output capacitance  
vs. collector-base voltage

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